

SCD240



Power Rectifier Diodes

Applications

- Power Supplies
- Uncontrolled Rectifiers
- Battery Chargers

Features

- Full blocking capability over wide temperature range
- Hermetic metal case with glass insulator
- Threaded Stud

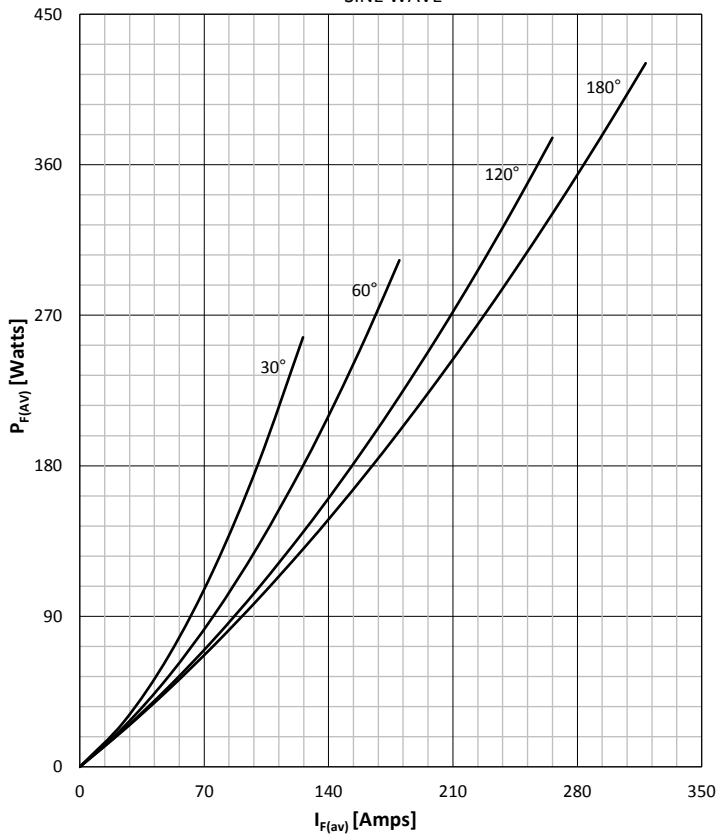
Key Parameters

V_{RRM}	= 1600V
$I_{F(AV)}$	= 320A
I_{FSM}	= 6000A
$V_{F(TO)}$	= 0.85V
r_F	= 0.60mΩ

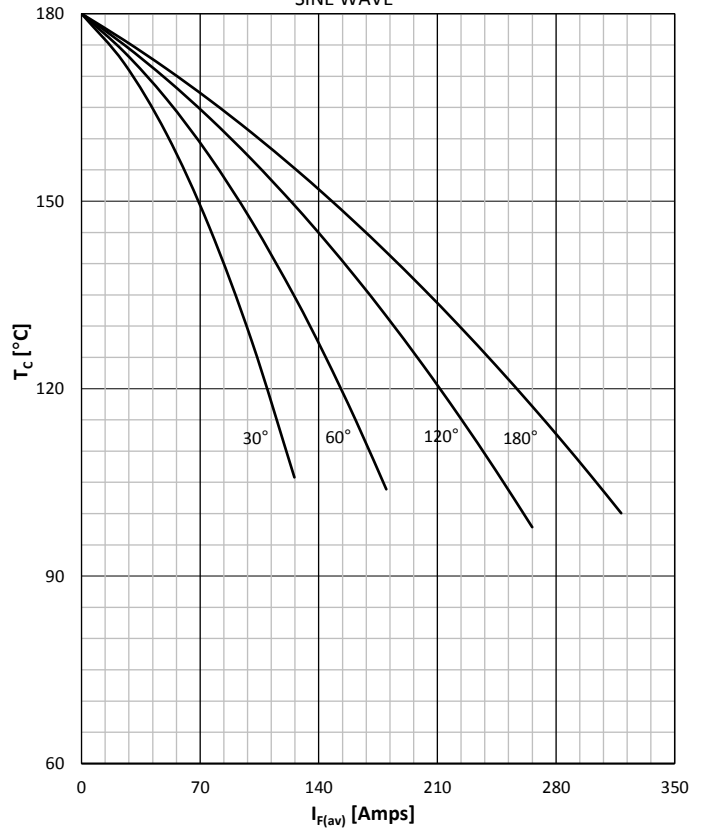
Symbol	Characteristic	Conditions	T_j [°C]	Value	Unit
BLOCKING					
V_{RRM}	Repetitive peak reverse voltage		180	200 - 1600	V
V_{RSM}	Non-repetitive peak reverse voltage		180	300 - 1700	V
I_{RRM}	Repetitive peak reverse current	$V = V_{RRM}$	180	30	mA
CONDUCTING					
$I_{F(AV)}$	Mean forward current	180° sin, 50 Hz, $T_c=100^\circ\text{C}$ $T_c=125^\circ\text{C}$		320 240	A
I_{FRMS}	RMS current			500	A
I_{FSM}	Surge forward current	Sine wave, 10 ms Without reverse voltage	25	6000	A
			180	5000	A
$I^2 t$	$I^2 t$	Sine wave, 10 ms Without reverse voltage	25	180000	A ² s
			180	125000	A ² s
V_F	Forward voltage	On-state current = 750A	180	1.30	V
$V_{F(TO)}$	Threshold voltage		180	0.85	V
r_F	Forward slope resistance		180	0.60	mΩ
MOUNTING					
$R_{th(j-c)}$	Thermal impedance, sin 180°	Junction to case		0.19	°C/W
$R_{th(c-h)}$	Thermal impedance	Case to heatsink		0.03	°C/W
T_j	Max. junction temperature			180	°C
T_{stg}	Storage temperature			-40 180	°C
M	Mounting torque			26	NM
W	Weight (Approx.)			250	gm

DISSIPATION CHARACTERISTICS

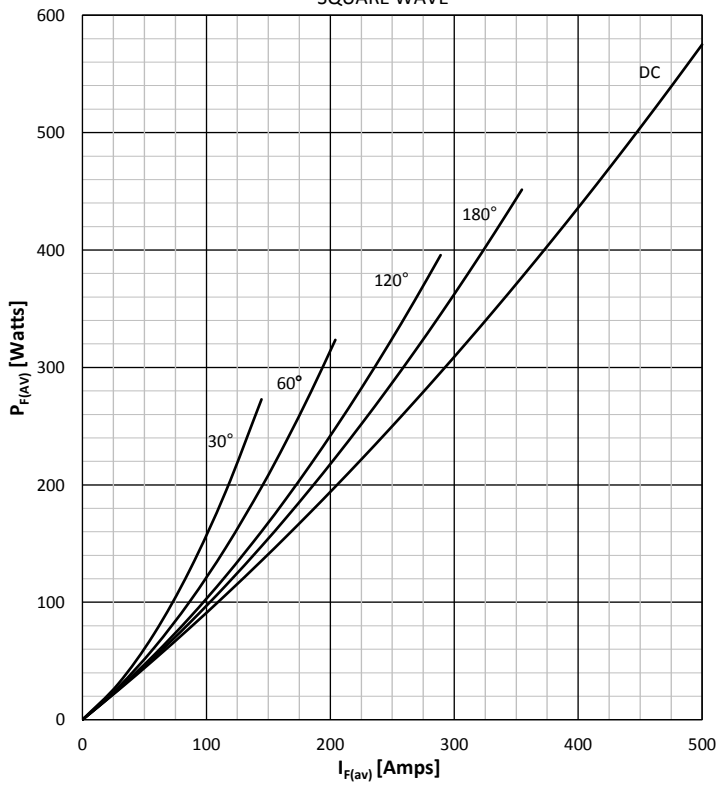
SINE WAVE


FORWARD CURRENT DERATING CURVE

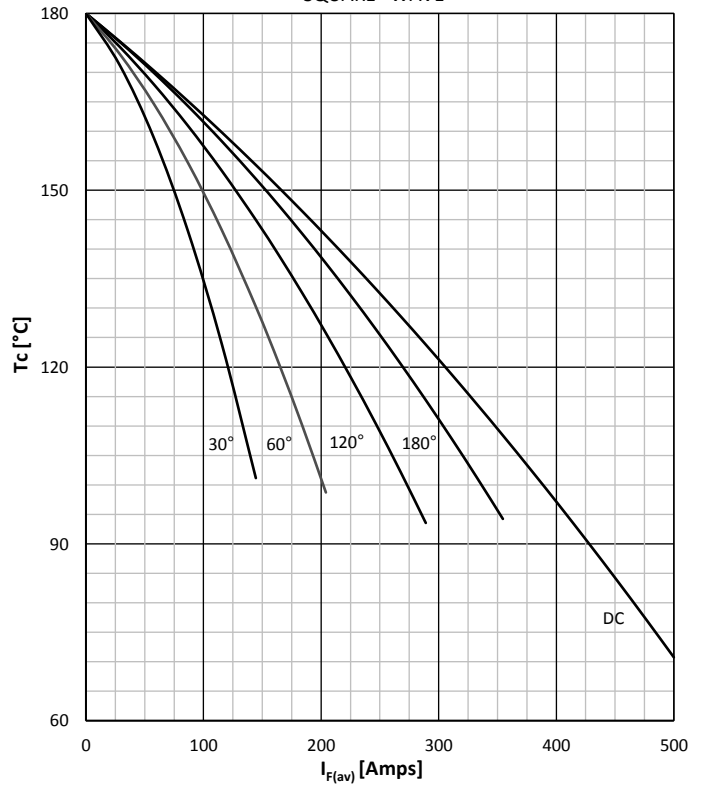
SINE WAVE

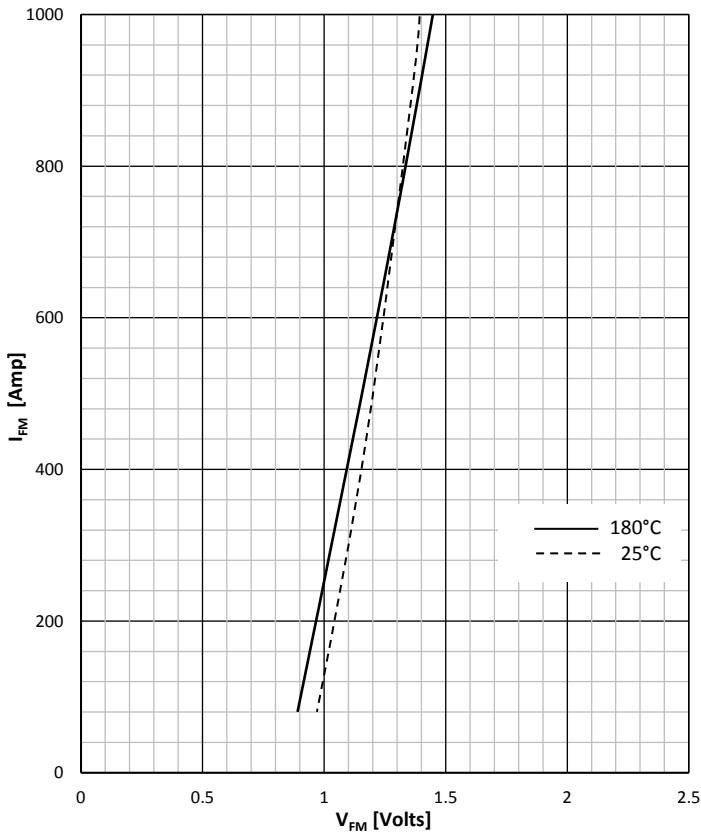
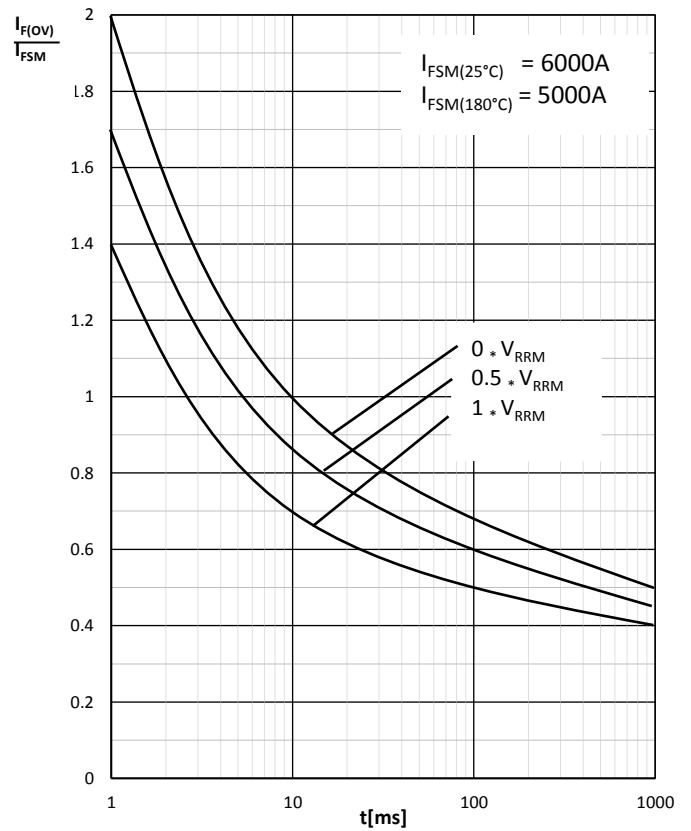
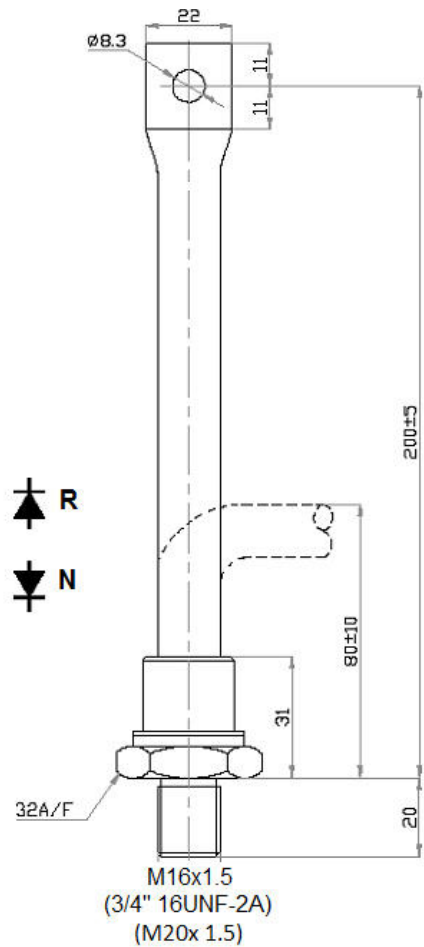
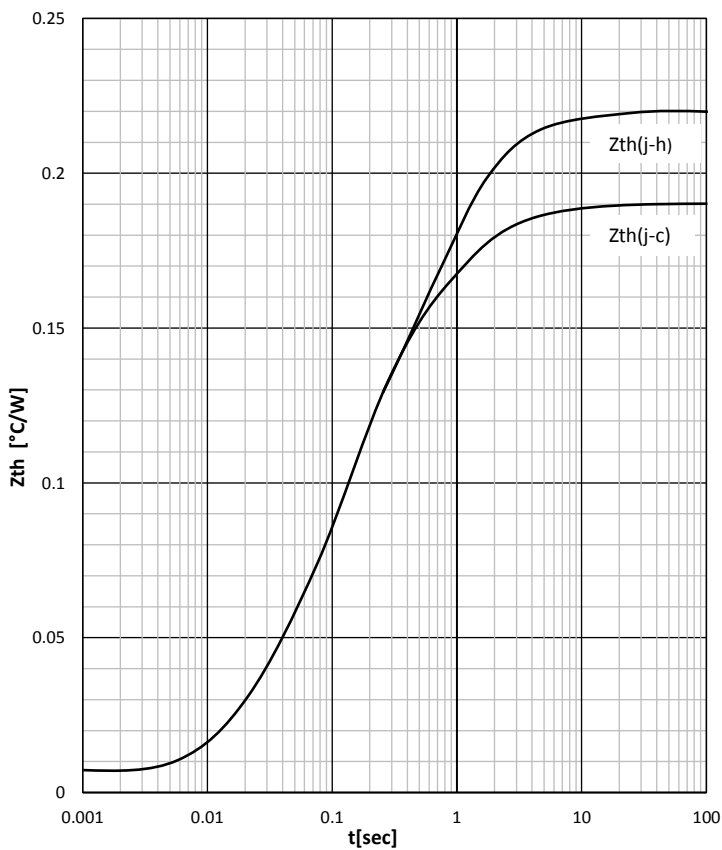

DISSIPATION CHARACTERISTICS

SQUARE WAVE


FORWARD CURRENT DERATING CURVE

SQUARE WAVE



FORWARD CHARACTERISTIC

SURGE CHARACTERISTICS

TRANSIENT THERMAL IMPEDANCE


Scomes srl reserves the right to change any specification without notice

issue:mar-2019